

Product data sheet

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NXP Semiconductors





Band-switching diode

BA277

FEATURES

- Small plastic SMD package
- Continuous reverse voltage: max. 35 V
- Continuous forward current: max. 100 mA
- Low diode capacitance: max. 1.2 pF
- Low diode forward resistance: max. 0.7 $\Omega.$

APPLICATIONS

- · Low loss band switching in VHF television tuners.
- Surface mount band-switching circuits.

DESCRIPTION

Planar high performance band-switching diode in a small plastic SOD523 (SC-79) SMD package.

PINNING

PIN	DESCRIPTION	
1	cathode	
2	anode	

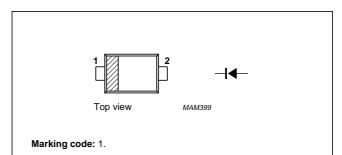


Fig.1 Simplified outline (SOD523; SC-79) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _R	continuous reverse voltage		_	35	V
I _F	continuous forward current		_	100	mA
P _{tot}	total power dissipation	T _s = 90 °C	_	715	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

ELECTRICAL CHARACTERISTICS

 $T_i = 25 \,^{\circ}C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V _F	forward voltage	I _F = 10 mA	1	V
I _R	reverse current	V _R = 25 V	50	nA
		V _R = 20 V; T _{amb} = 75 °C	1	μA
C _d	diode capacitance	$f = 1 \text{ MHz}; V_R = 6 \text{ V}; \text{ note } 1; \text{ see Fig.2}$	1.2	pF
r _D	diode forward resistance	$I_F = 2 \text{ mA}$; f = 100 MHz; note 1; see Fig.3	0.7	Ω

Note

1. Guaranteed on AQL basis: inspection level S4, AQL 1.0.

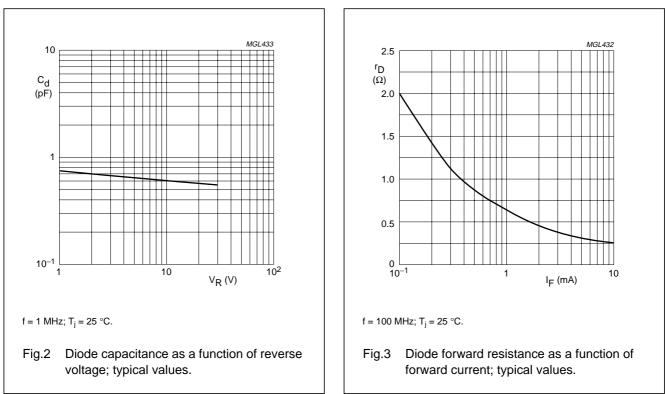
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-s}	thermal resistance from junction to soldering-point		K/W

Band-switching diode

BA277





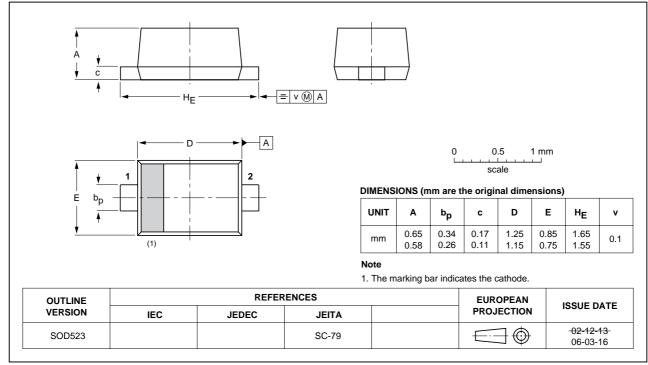
Band-switching diode

BA277

SOD523

PACKAGE OUTLINE





Legal information

Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Revision history

Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
BA277_N_2	20080107	Product data sheet	-	BA277_1	
Modifications: • Package outline on page 4 changed					
BA277_1 (9397 750 03793)	19980506	Product specification	-	-	

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Date of release: 7 January 2008 Document identifier: BA277_N_2